**New Product** 

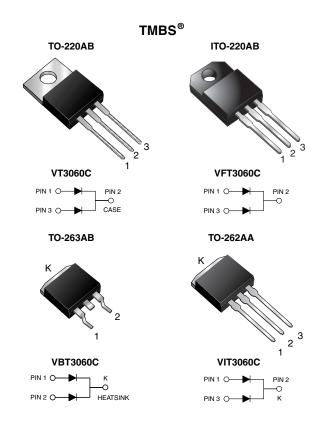


## VT3060C, VFT3060C, VBT3060C & VIT3060C

Vishay General Semiconductor

## **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.38$  V at  $I_F = 5$  A



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
V <sub>RRM</sub>	60 V					
I <sub>FSM</sub>	170 A					
$V_F$ at $I_F$ = 15 A	0.57 V					
T <sub>J</sub> max.	150 °C					

## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF COMPLIANT maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

### MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER		VT3060C	VFT3060C	VBT3060C	VIT3060C	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	60					
Maximum average forward rectified currentper device(fig. 1)per diode	I <sub>F(AV)</sub>	30 15				А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	170			А		
Non-repetitive avalanche energy at $T_J$ = 25 °C, L = 60 mH per diode	E <sub>AS</sub>	180					
Peak repetitive reverse current at $t_p = 2 \mu s$ , 1 kHz, T <sub>J</sub> = 38 °C ± 2 °C per diode	I <sub>RRM</sub>	1.0				А	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500				V	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150				°C	

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### **New Product**

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	l <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	60 (minimum)	-	V		
Instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5 A I <sub>F</sub> = 7.5 A I <sub>F</sub> = 15 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.47 0.51 0.60	- - 0.70	v		
	I <sub>F</sub> = 5 A I <sub>F</sub> = 7.5 A I <sub>F</sub> = 15 A	T <sub>A</sub> = 125 °C		0.38 0.44 0.57	- - 0.65			
Reverse current per diode <sup>(2)</sup>	V <sub>R</sub> = 60 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	- 20	1.2 45	mA		

#### Notes:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT3060C	VFT3060C	VBT3060C	VIT3060C	UNIT
Typical thermal resistance	per diode per device	$R_{ ext{ heta}JC}$	2.5 1.7	6.0 4.8	2.5 1.7	2.5 1.7	°C/W

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT3060C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VFT3060C-E3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VBT3060C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VBT3060C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT3060C-E3/4W	1.46	4W	50/tube	Tube			

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

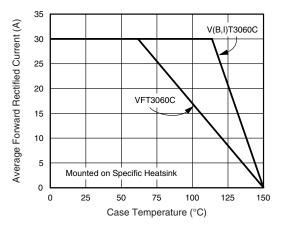


Figure 1. Maximum Forward Current Derating Curve

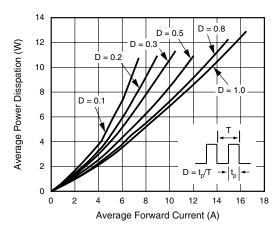


Figure 2. Forward Power Dissipation Characteristics Per Diode



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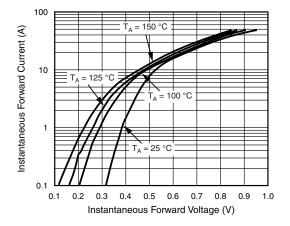


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

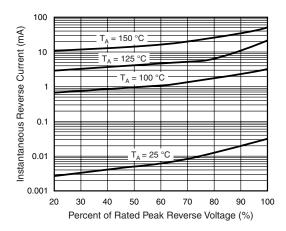


Figure 4. Typical Reverse Characteristics Per Diode

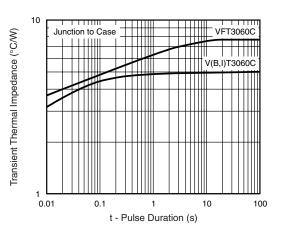


Figure 5. Typical Transient Thermal Impedance Per Diode

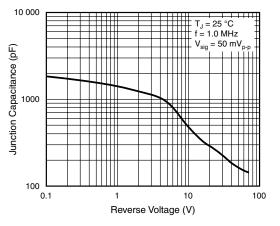
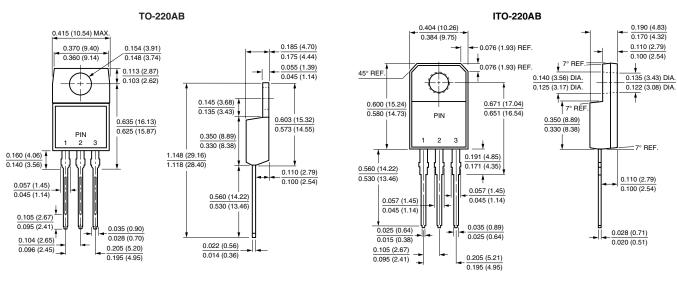


Figure 6. Typical Junction Capacitance Per Diode

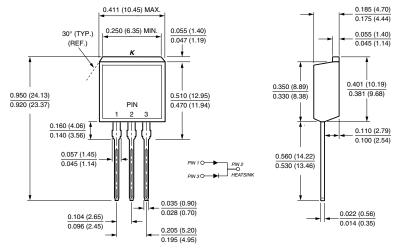
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



**TO-262AA** 



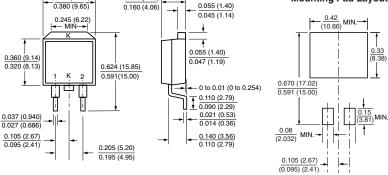
TO-263AB

0.190 (4.83)

0.41 (10.45)



 $\frac{0.33}{(8.38)}$ MIN



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